

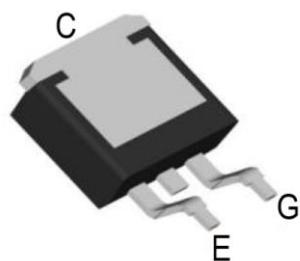
## **SSC65T50GT6**

### Trench FSII Fast IGBT

#### ➤ Features

$V_{CES}$	$V_{GES}$	$I_c$
650V	$\pm 20V$	80A@25°C
		50A@100°C

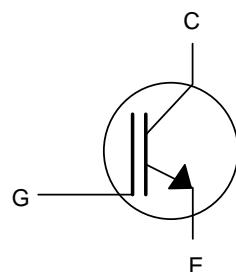
#### ➤ Pin Configuration



TO-263-3L (Bottom View)

#### ➤ Description

Using trench design and advanced FS (Field Stop) second generation technology, the 650V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation.



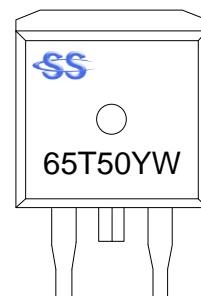
Pin Configuration

#### ➤ Applications

- Welding Machines
- PFC Circuits
- UPS
- Power Inverters

#### ➤ Ordering Information

Device	Package	Shipping
SSC65T50GT6	TO-263-3L	50/Tube
Minimum Purchase Quantity: 1K/Box		



Marking

(YW: Internal Traceability Code)

➤ Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$V_{CES}$	Collector-Emitter Voltage	650	V
$V_{GES}$	Gate-Emitter Voltage	$\pm 20$	V
$I_c$	Collector Current	$T_c=25^\circ\text{C}$	80
		$T_c=100^\circ\text{C}$	50
$I_{Cpuls}$	Pulsed Collector Current, $t_p$ limited by $T_{Jmax}$	150	A
-	Turn off safe operating area, $V_{CE} = 1200\text{V}, T_J = 150^\circ\text{C}$	150	A
$P_D$	Power Dissipation <sup>a</sup>	$T_A=25^\circ\text{C}$	266
		$T_A=70^\circ\text{C}$	170
$T_J$	Operating Junction and Storage Temperature Range	-55~150	$^\circ\text{C}$
$T_{STG}$	Operating Junction and Storage Temperature Range	-55~150	$^\circ\text{C}$
$T_L$	Maximum Temperature for Soldering	260	$^\circ\text{C}$

➤ Thermal Resistance Ratings ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance	50	$^\circ\text{C}/\text{W}$
$R_{\theta JC}$	Junction-to-Case Thermal Resistance	0.47	

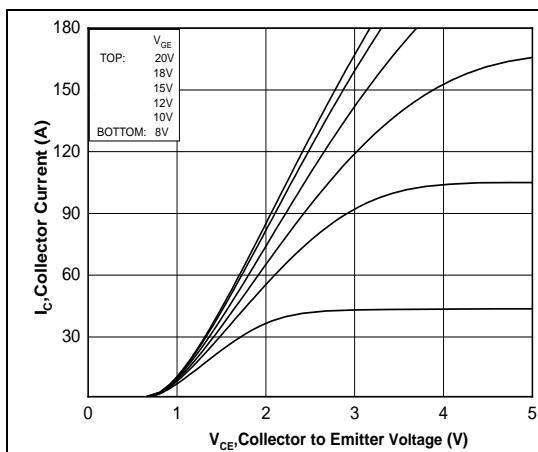
Note:

- The maximum current rating is package limited.

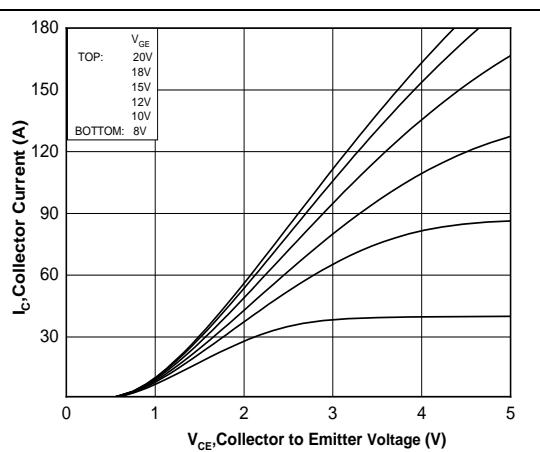
➤ Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(\text{BR})\text{CES}}$	Collector-Emitter Breakdown Voltage	$V_{\text{GE}} = 0\text{V}, I_C = 0.25\text{mA}$	650			V
$I_{\text{CES}}$	Collector-Emitter Leakage Current	$V_{\text{GE}}=0\text{V}, V_{\text{CE}}=650\text{V}, T_J=25^\circ\text{C}$			1	uA
		$V_{\text{GE}}=0\text{V}, V_{\text{CE}}=650\text{V}, T_J=150^\circ\text{C}$		5	100	uA
$I_{\text{GES(F)}}$	Gate to Emitter Forward Leakage	$V_{\text{GE}} = +20\text{V}, V_{\text{CE}} = 0\text{V}$			100	nA
$I_{\text{GES(R)}}$	Gate to Emitter Reverse Leakage	$V_{\text{GE}} = -20\text{V}, V_{\text{CE}} = 0\text{V}$			-100	nA
$V_{\text{CE}(\text{sat})}$	Collector-Emitter Saturation Voltage	$I_C=50\text{A}, V_{\text{GE}}=15\text{V}, T_J=25^\circ\text{C}$		1.6		V
		$I_C=50\text{A}, V_{\text{GE}}=15\text{V}, T_J=125^\circ\text{C}$		1.9		V
		$I_C=50\text{A}, V_{\text{GE}}=15\text{V}, T_J=150^\circ\text{C}$		2.0		V
$V_{\text{GE}(\text{th})}$	Gate Threshold Voltage	$I_C = 1\text{mA}, V_{\text{CE}} = V_{\text{GE}}$	4	5	6	V
$G_{\text{FS}}$	Transconductance	$V_{\text{CE}} = 20\text{V}, I_C = 50\text{A}$		26		S
$C_{\text{ies}}$	Input Capacitance	$V_{\text{CE}} = 25\text{V}, V_{\text{GE}} = 0\text{V}, f = 1\text{MHz}, T_J = 25^\circ\text{C}$		1701		pF
$C_{\text{oes}}$	Output Capacitance			117		
$C_{\text{res}}$	Reverse Transfer Capacitance			101		
$T_{\text{D(ON)}}$	Turn-on delay time	$T_J=25^\circ\text{C}, V_{\text{CC}}=400\text{V}, I_C=50\text{A}, V_{\text{GE}}=0/15\text{V}, R_g=10\Omega, \text{Inductive Load}$		19		ns
$T_r$	Rise time			38		
$T_{\text{D(OFF)}}$	Turn-off delay time			249		
$T_f$	Fall time			56		mJ
$E_{\text{on}}$	Turn-On Switching Loss			1.34		
$E_{\text{off}}$	Turn-Off Switching Loss			1.49		
$E_{\text{ts}}$	Total Switching Loss			2.83		mJ
$T_{\text{D(ON)}}$	Turn-on delay time	$T_J=150^\circ\text{C}, V_{\text{CC}}=400\text{V}, I_C=50\text{A}, V_{\text{GE}}=0/15\text{V}, R_g=10\Omega, \text{Inductive Load}$		18		ns
$T_r$	Rise time			43		
$T_{\text{D(OFF)}}$	Turn-off delay time			265		
$T_f$	Fall time			85		mJ
$E_{\text{on}}$	Turn-On Switching Loss			1.53		
$E_{\text{off}}$	Turn-Off Switching Loss			1.72		
$E_{\text{ts}}$	Total Switching Loss			3.25		nC
$Q_G$	Total Gate Charge	$V_{\text{CC}} = 300\text{V}, I_C = 50\text{A}, V_{\text{GE}} = 0/15\text{V}$		158		nC
$Q_{\text{GE}}$	Gate to Emitter Charge			13		
$Q_{\text{GC}}$	Gate to Collector Charge			32		

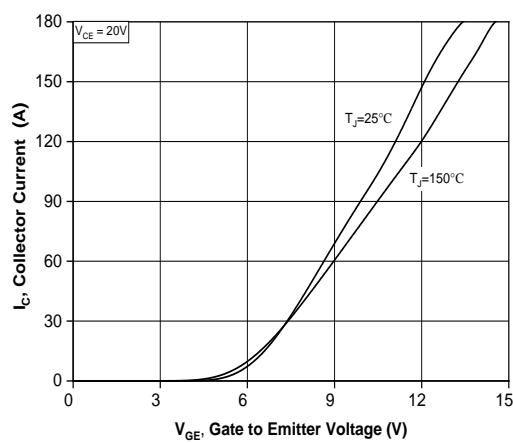
➤ Typical Performance Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise noted)



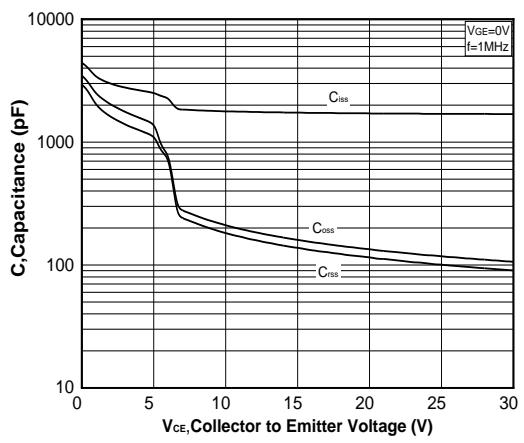
**Figure 1. Output Characteristics( $T_J=25^\circ\text{C}$ )**



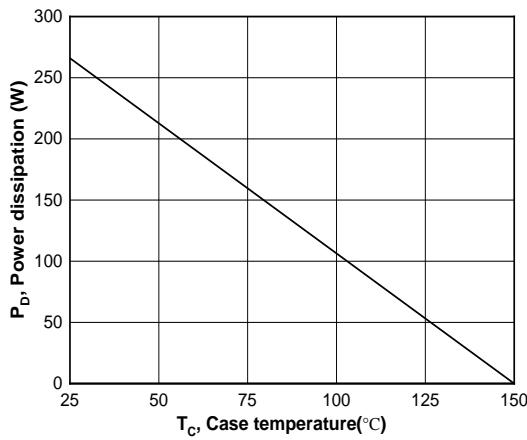
**Figure 2. Output Characteristics( $T_J=150^\circ\text{C}$ )**



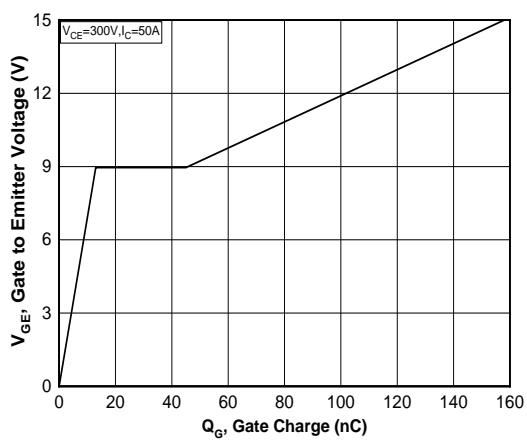
**Figure 3. Typical transfer characteristic  
( $T_J=25^\circ\text{C}$ )**



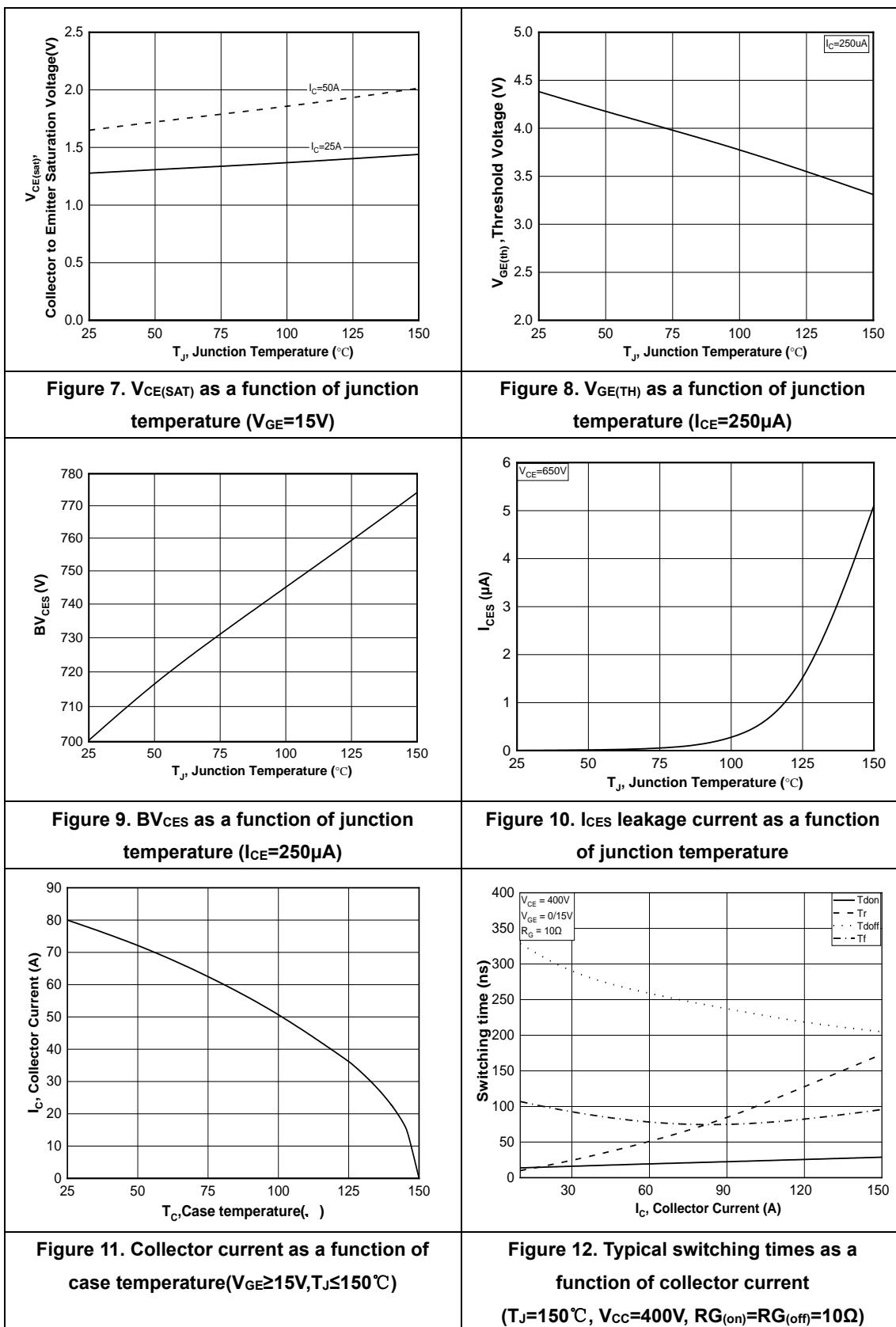
**Figure 4. Capacitance characteristic  
( $V_{GE}=0\text{V}$ ,  $f=1\text{MHz}$ )**

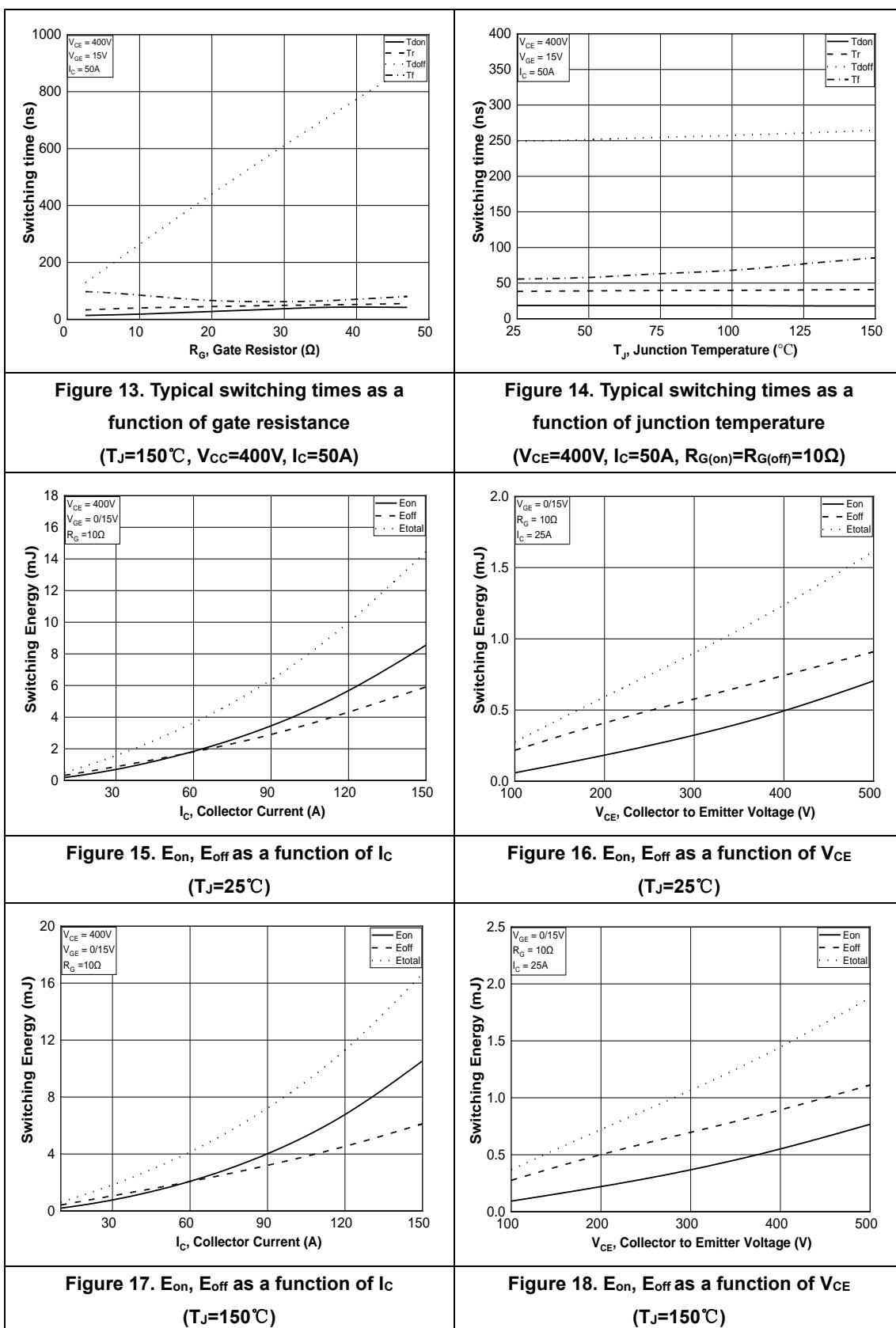


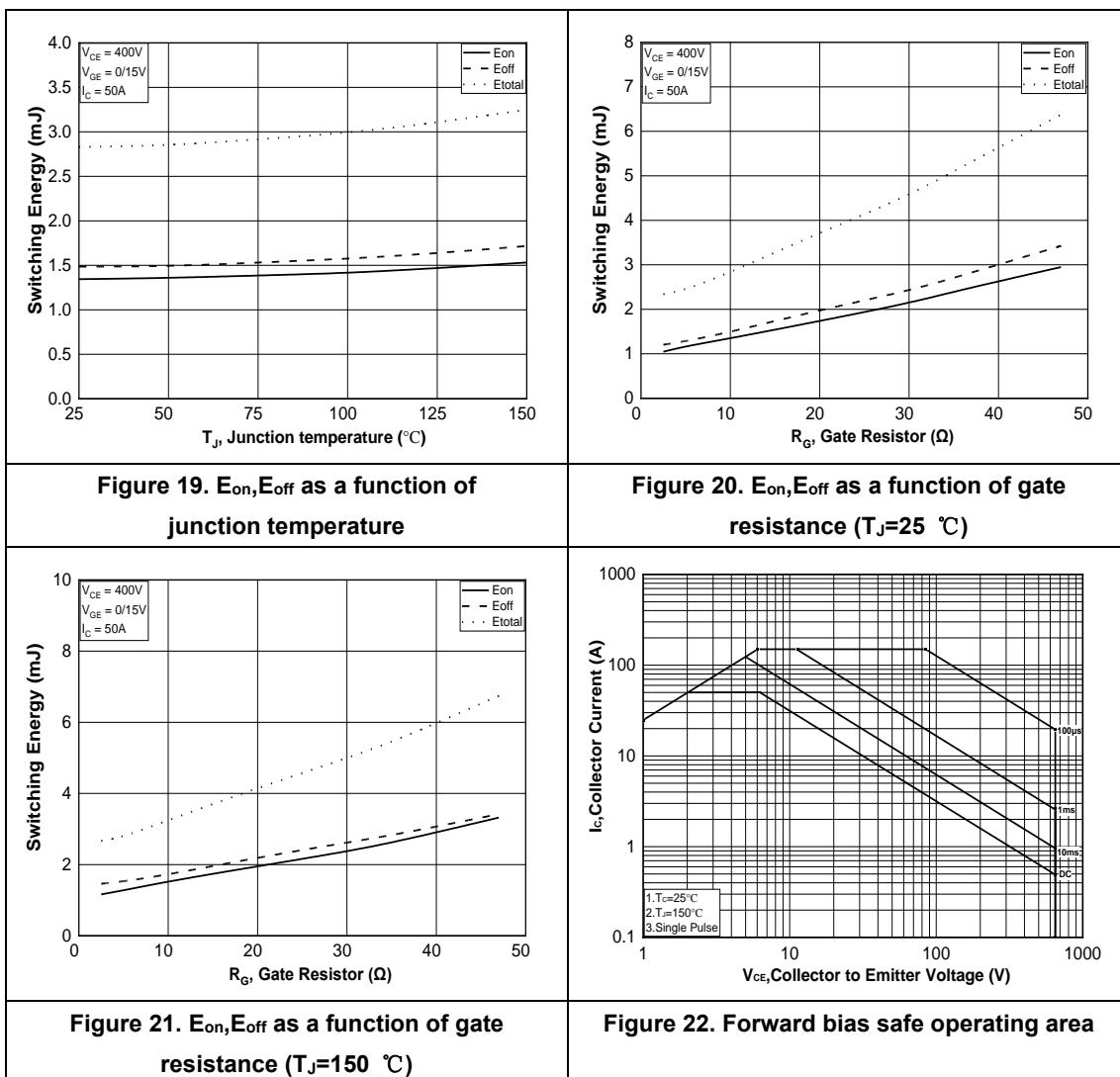
**Figure 5. Power dissipation as a function of  
case temperature ( $T_J \leq 175^\circ\text{C}$ )**



**Figure 6. Typical gate charge ( $I_c=50\text{A}$ )**

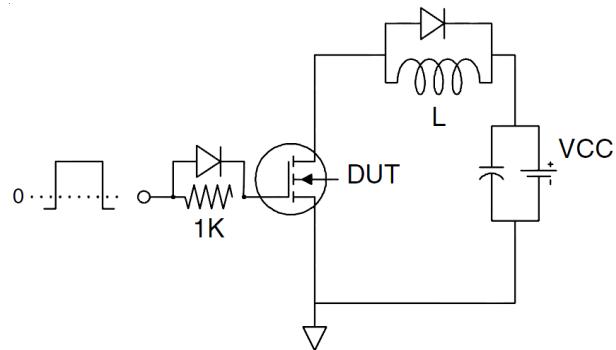




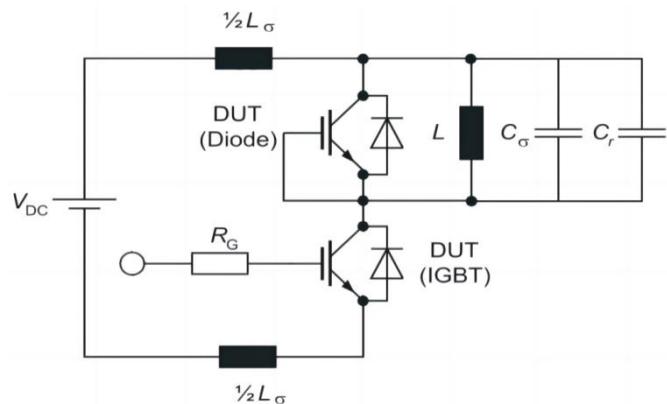


➤ **Test Circuit**

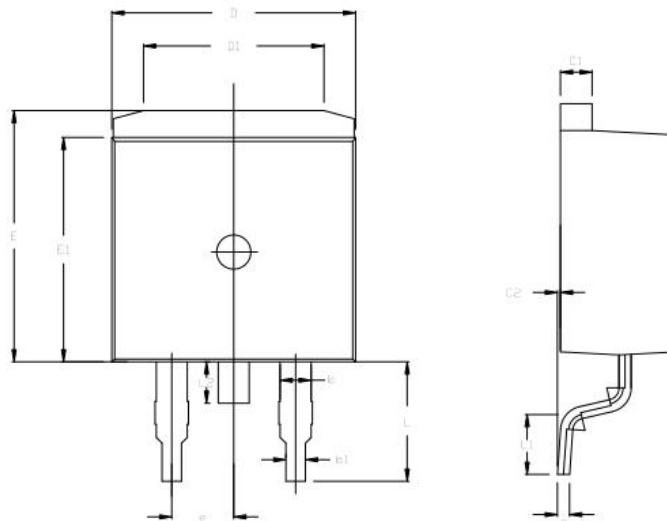
**(1) Gate Charge Test Circuit**



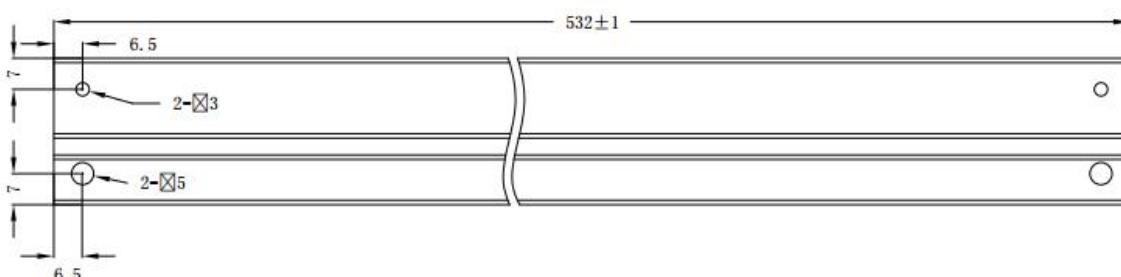
**(2) Switch Time Test Circuit**



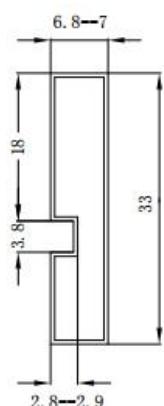
➤ Package Information



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	4.40	--	4.60
b	1.20	--	1.36
b1	0.70	--	0.90
C	0.48	--	0.53
C1	1.28	--	1.32
C2	0.04	0.12	0.20
D	9.80	10.00	10.20
D1	7.25	7.40	7.55
E	10.20	10.30	10.40
E1	9.10	9.20	9.30
e	--	2.54	--
L	4.70	4.90	5.10
L1	2.40	2.60	2.80
L2	1.50	1.70	1.90



T=0.5 ± 0.1



技术要求:

1. 材料: 透明PVC
2. 表面电阻:  $10E5 \sim 10E10$  OHMS/SQ
3. 未注尺寸公差±0.3
4. 黑色钉子由厂家出货时塞于左端



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